

PAN FILE DEVELOPMENT REPORT

ZNSHINE PV-TECH CO. LTD.

SOLAR MODULE: ZXP6-D72-325/P,
ZXP6-D72-320/P

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INTERTEK TESTING SERVICES SHANGHAI

Address: 1-2F, No.2, Alley 1218, Wan Rong Road, Shanghai,
China

EVALUATION OF

ZXP6-D72-325/P, ZXP6-D72-320/P

RENDERED by

Znshine PV-Tech Co. Ltd.

Date of receipt of the test item: 2018-05-07

Date of performance of the test item: 2018-05-10 ~ 2018-07-02

Applicant:

Znshine PV-Tech Co. Ltd.

Contact: Yang Jian

Phone: +86 519 68220253

Email: yangjian@znshinesolar.com

Manufacturer:

Znshine PV-Tech Co. Ltd.

Contact: Yang Jian

Phone: +86 519 68220253

Email: yangjian@znshinesolar.com

Report Reference No. : 180302718SHA-003

Compiled by : Sherwin Zhu *Sherwin Zhu*

Approved by : Ken Gu *Ken Gu*

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CONTENT

EXECUTIVE SUMMARY

1.0 APPROACH

- 1.1 Measured Data
- 1.2 Base Case PAN File
- 1.3 Optimization

2.0 RESULTS

- 2.1 ZXP6-D72-325/P, ZXP6-D72-320/P
 - 2.1.1 Measured Data
 - 2.1.2 Base Case PAN File
 - 2.1.3 Optimized PAN File

3.0 APPENDIX PARTRESULTS

Appendix A. Datasheet of ZXP6-D72-325/P, ZXP6-D72-320/P

4.0 LIST OF TABLES

- Table1 Goodness of Fit Metrics for ZXP6-D72-325/P, ZXP6-D72-320/P PAN File
- Table2 Measured Pre-LID (average) Maximum Powers (Pmp) at Test Conditions for ZXP6-D72-325/P, ZXP6-D72-320/P
- Table3 Scaled Pre-LID Maximum Powers (Pmp) at Test Conditions for ZXP6-D72-325/P, ZXP6-D72-320/P
- Table4 Summary of Inputs and Sources for Base Case Model
- Table5 Summary of Adjusted Inputs for Optimized ZXP6-D72-325/P, ZXP6-D72-320/P
- Table6 Goodness of Fit Metrics for ZXP6-D72-325/P, ZXP6-D72-320/P PAN File

5.0 LIST OF FIGURES

- Figure1 PVsyst Efficiency Curves for the Base Case of ZXP6-D72-325/P, ZXP6-D72-320/P
- Figure2 PVsyst Efficiency Curves for the Optimized ZXP6-D72-325/P, ZXP6-D72-320/P PAN File

Executive Summary

Znshine PV-Tech Co. Ltd. contracted Intertek Testing Services NA (Intertek) to create a photovoltaic (PV) module characterization file (known as a “PAN” File) for use in PVsyst modeling software for the ZXP6-D72-325/P, ZXP6-D72-320/P crystalline silicon module.

Intertek used its test measurements for three samples of the ZXP6-D72-325/P module, which quantified the performance metrics of the sample after Light-Induced Degradation (i.e. Pre-LID) at multiple irradiance and temperature conditions, according to the testing standard IEC61853-1. ZXP6-D72-320/P is identical to ZXP6-D72-325/P except the output power. And it can be considered that there is an excellent uniformity of these two models’ electrical characteristic. Intertek created a Base Case PAN file for the module using the module datasheet and PVsyst defaults. After evaluating the fit of the Base Case PAN file efficiency curves to the measured efficiency curves, Intertek adjusted the PAN file input parameters to obtain the closest fit of PVsyst modeled efficiency curves to the Intertek measured curves, resulting in the final Optimized PAN file.

Intertek fitting metric to assess the improvement achieved – Root-Sum-Square (RSS), which assesses the absolute deviation between efficiencies. This metrics is presented in Table 1 for the Optimized PAN file of each model.

Table 1 Goodness of Fit Metrics ZXP6-D72-325/P, ZXP6-D72-320/P PAN File

Model	Optimized RSS	Relative Efficiency
ZXP6-D72-325/P	0.90 %	16.57 %
ZXP6-D72-320/P	0.90 %	16.32 %

The Optimized PAN file is designed to be used in PVsyst software version 6.5.2 for modeling the expected performance of the given module. This PAN file is provided separately as “.PAN” file.

Note to PAN file users: This PAN file is derived from Pre-LID laboratory measurements.

1.0 Approach

The purpose of this effort was to create a PVsyst-compatible PAN file that more accurately represents the ZXP6-D72-325/P, ZXP6-D72-320/P in tested conditions.

In order to accomplish this, Intertek took the following approach:

1. Measured Data: Process raw measured data from test lab and develop “Measured” efficiency curves for the ZXP6-D72-325/P under certain irradiance and module temperatures. Since the measured data represented a module at nominal power, the efficiency curves were scaled to represent module nominal rating (referred to as “Scaled Measured”).
2. Base Case PAN File: Create a Base Case PAN file using parameters from the module datasheet and default values in PVsyst. Compare the resulting Base Case “Modeled” efficiency curves to the measured efficiency curves from step 1 to determine the extent of deviation.
3. Optimization: Adjust PAN file parameters until the Modeled efficiency curves generated by PVsyst match the measured curves as closely as possible.

1.1 Measured Data

Intertek measured three samples ZXP6-D72-325/P module, which quantified the performance metrics of the sample module after Light-Induced Degradation (i.e. Pre-LID) at multiple irradiance and temperature test conditions, according to the testing standard IEC61853-1.

Test conditions:

The testing standard IEC 61853-1 required test conditions at four module temperatures:

15°C, 25°C, 50°C, 75°C

And seven irradiances:

100W/m², 200W/m², 400W/m², 600W/m², 800W/m², 1000W/m², 1100W/m²

The test results for the Pre-LID ZXP6-D72-325/P module resulted in maximum power (P_{mp}) at standard test conditions (STC = 25 °C and 1000W/m²). These were a little different with the datasheet nominal power of rating, but were within the tolerance of sample ratings.

Table 2 shows the test data (average) for the Pre-LID ZXP6-D72-325/P module, which serves as the basis for creating efficiency curves for the PAN file in this report.

Table 2 Measured Pre-LID (average) Maximum Powers at Test Conditions for the ZXP6-D72-325/P

ZXP6-D72-325/P

IRRADIANCE (W/m ²)	Spectrum	Pmp at 15°C (W)	Pmp at 25°C (W)	Pmp at 50°C (W)	Pmp at 75°C (W)
100	AM1.5	31.194	29.692	-	-
200	AM1.5	65.229	62.379	-	-
400	AM1.5	133.613	127.829	116.784	-
600	AM1.5	202.022	193.660	173.324	152.643
800	AM1.5	270.644	259.261	234.254	206.997
1000	AM1.5	340.224	327.153	293.714	260.501
1100	AM1.5	-	359.377	322.277	285.464

Since the Pre-LID test data measured were different with module nominal ratings, Intertek scaled the Pmp measurement to standard test condition (STC) to create scaled measured efficiency curves. Efficiency curves describe module efficiency as a function of module temperature and irradiance at various conditions determined by the IEC 61853 testing standard. Efficiency is calculated as:

$$\text{Efficiency} = \frac{\text{Module Rating [Wp]}}{\text{Module Area [m}^2\text{]} * \text{Irradiance } \left[\frac{\text{W}}{\text{m}^2}\right]}$$

Previous parametric data has shown that for a given manufacturer, the shape of the efficiency curves is within the tolerance range of declaring of manufacturer. Therefore, Intertek scaled the test data to module rating by applying a linear scaling factor. These measured efficiency curves were then used to verify the accuracy of the PAN file in the next steps.

1.2 BASE CASE PAN FILE

In order to create a Base Case PAN file in PVsyst, Intertek used the Znshine PV-Tech Co. Ltd. module datasheet (see Appendix A) for the following PVsyst inputs: module area, short-circuit current (Isc), open-circuit voltage (Voc), maximum power current (Imp), maximum power voltage (Vmp) and the temperature coefficients of Isc and Pmp. The other necessary module parameters were left at PVsyst defaults.

The Modeled efficiency curves generated by PVsyst from these Base Case PAN file parameters were then compared to the Measured curves based on the test data.

The comparison of Measured curves with those Modeled was performed using following metrics to quantify deviation:

Root Sum Square (RSS) Deviation : The agreement between the Modeled and Measured efficiency curves was evaluated by analyzing the sum of the square of differences between the two, called the root sum square (RSS) Deviation.

1.3 OPTIMIZATION

After determining the discrepancy between the Measured and Modeled efficiency curves for the Base Case, Intertek adjusted PAN file parameters in order to force the Modeled efficiency curves generated by PVsyst to better match the Measured efficiency curves seen in the lab.

Using an algorithm for optimization, the PAN file was iteratively refined to minimize the deviation between these efficiency curves, with the goal of minimizing the RSS primarily and other secondarily. The adjusted parameters are documented in the Results section.

Since Intertek's optimized PAN file uses high-accuracy laboratory measurements of irradiance and temperature dependent PV module performance as the references for optimization of the PAN file, the accuracies of the resulting PVsyst simulations are improved.

2.0 RESULTS

The results and parameters for the ZXP6-D72-325/P and ZXP6-D72-320/P module are presented in the following sections.

2.1 ZXP6-D72-325/P, ZXP6-D72-320/P

2.1.1 Measured Data

Table 3 documents the measured Pre-LID module powers at Test Conditions, after scaling to the rated nominal power of the module.

Table 3 Scaled Pre-LID Maximum Powers at Test Conditions for ZXP6-D72-325/P and ZXP6-D72-320/P module

ZXP6-D72-325/P

IRRADIANCE (W/m ²)	Spectrum	Pmp at 15°C (W)	Pmp at 25°C (W)	Pmp at 50°C (W)	Pmp at 75°C (W)
100	AM1.5	30.988	29.497	-	-
200	AM1.5	64.800	61.968	-	-
400	AM1.5	132.733	126.988	116.016	-
600	AM1.5	200.693	192.386	172.183	151.638
800	AM1.5	268.863	257.555	232.713	205.634
1000	AM1.5	337.985	325.000	291.781	258.787
1100	AM1.5	-	357.012	320.157	283.586

ZXP6-D72-320/P

IRRADIANCE (W/m ²)	Spectrum	Pmp at 15°C (W)	Pmp at 25°C (W)	Pmp at 50°C (W)	Pmp at 75°C (W)
100	AM1.5	30.512	29.043	-	-
200	AM1.5	63.803	61.015	-	-
400	AM1.5	130.691	125.034	114.231	-
600	AM1.5	197.605	189.426	169.534	149.305
800	AM1.5	264.727	253.592	229.132	202.471
1000	AM1.5	332.785	320.000	287.292	254.805
1100	AM1.5	-	351.519	315.231	279.223

2.1.2 Base Case PAN File

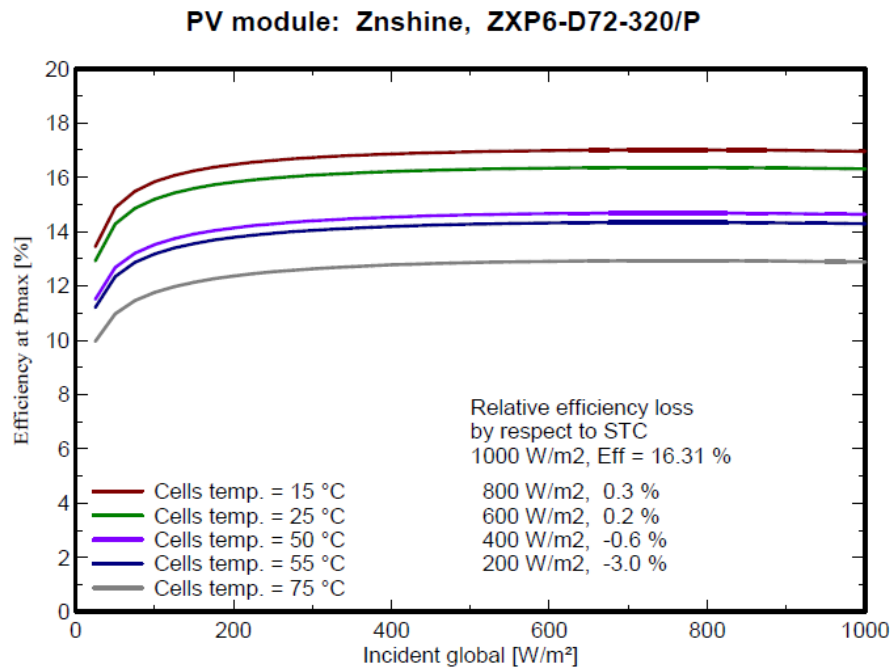
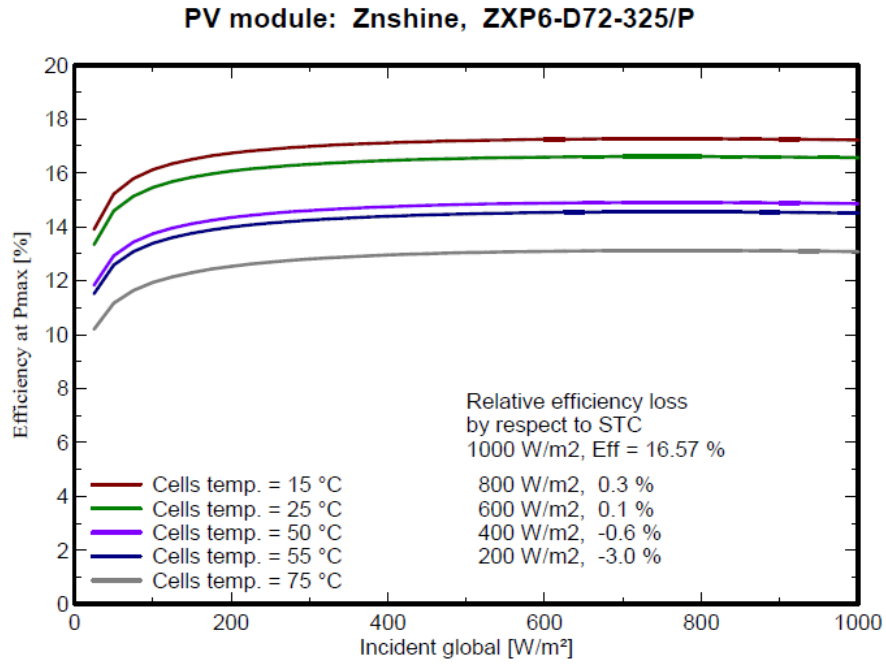
Table 4 summarizes the PVsyst inputs for the Base Case PAN file. Figure 1 shows the efficiency curves of the Base Case PAN file generated by PVsyst.

Table 4 Summary of inputs and Sources for Base Case Model

ZXP6-D72-325/P	VALUE	SOURCE
Isc (A)	9.27	Datasheet
Voc (V)	45.55	Datasheet
Imp (A)	8.71	Datasheet
Vmp (V)	37.32	Datasheet
Temp. Coeff. Isc (%/°C)	0.06	Datasheet
Temp. Coeff Pmp (%/°C)	-0.41	Datasheet
Shunt Resistance Rsh (Ohm)	350	PVsyst Default
Series Resistance Rs (Ohm)	0.337	PVsyst Default
Rshunt at Ginc=0 (Ohm)	1400	PVsyst Default
Rshunt Exponential Parameter	5.5	PVsyst Default

ZXP6-D72-320/P	VALUE	SOURCE
Isc (A)	9.21	Datasheet
Voc (V)	45.33	Datasheet
Imp (A)	8.62	Datasheet
Vmp (V)	37.32	Datasheet
Temp. Coeff. Isc (mA/°C)	0.06	Datasheet
Temp. Coeff Pmp (%/°C)	-0.41	Datasheet
Shunt Resistance Rsh (Ohm)	350	PVsyst Default
Series Resistance Rs (Ohm)	0.351	PVsyst Default
Rshunt at Ginc=0 (Ohm)	1200	PVsyst Default
Rshunt Exponential Parameter	5.5	PVsyst Default

Figure 1 PVsyst Efficiency Curves for the Base Case ZXP6-D72-325/P and ZXP6-D72-320/P



2.1.3 Optimized PAN File

Table 5 summarizes the adjusted PVsyst inputs for the Optimized PAN file. Figure 2 shows the corresponding efficiency curves generated by PVsyst.

Table 5 Summary of Adjusted Inputs for Optimized ZXP6-D72-325/P and ZXP6-D72-320/P PAN File

ZXP6-D72-325/P	VALUE
Temp. Coeff Pmp (%/°C)	-0.406
Series Resistance Rs (Ohm)	0.376
Shunt Resistance Rsh (Ohm)	350
Rshunt at Ginc=0 (Ohm)	1400

ZXP6-D72-320/P	VALUE
Temp. Coeff Pmp (%/°C)	-0.406
Series Resistance Rs (Ohm)	0.387
Shunt Resistance Rsh (Ohm)	350
Rshunt at Ginc=0 (Ohm)	1200

IAM defined:

$\theta / ^\circ$	0	20	40	60	70	75	80	85
IAM	1	1	0.98	0.93	0.86	0.79	0.65	0.23

Figure 2 PVsyst Efficiency Curves for the Optimized ZXP6-D72-325/P and ZXP6-D72-320/P PAN File

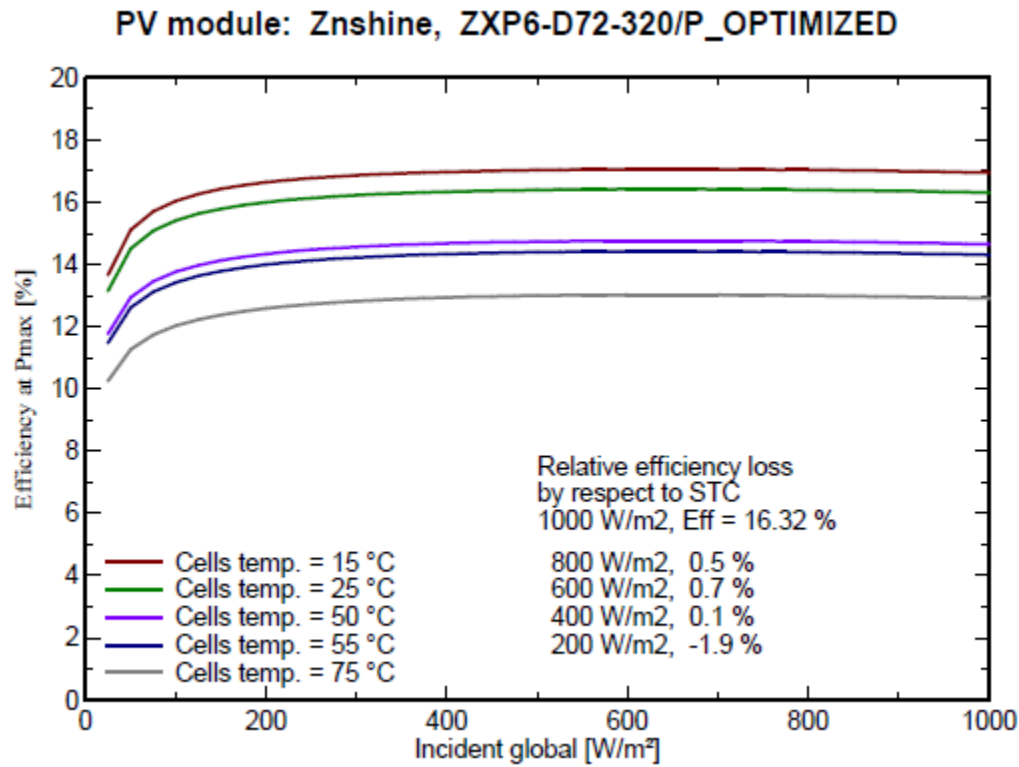
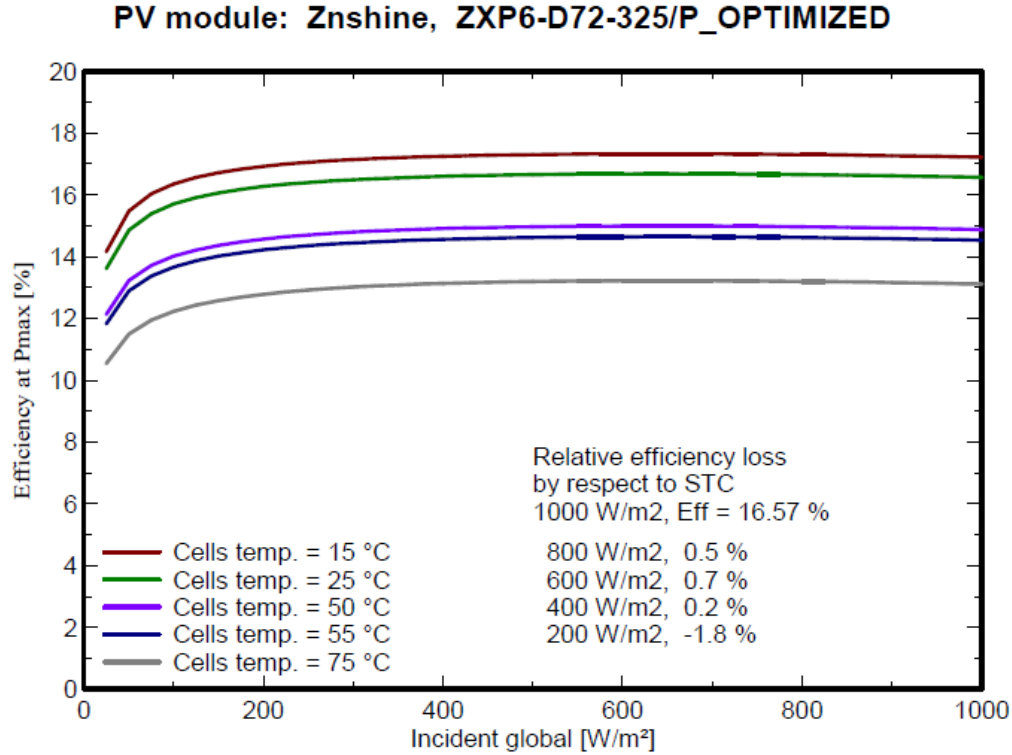


Table 6 shows the metrics of deviation from the optimized PAN file.

Table 6 Goodness of Fit Metrics for ZXP6-D72-325/P, ZXP6-D72-320/P PAN File

Model	Optimized RSS	Relative Efficiency
ZXP6-D72-325/P	0.90 %	16.57 %
ZXP6-D72-320/P	0.90 %	16.32 %

Note to PAN file users: This PAN file was derived from Pre-LID laboratory measurements.

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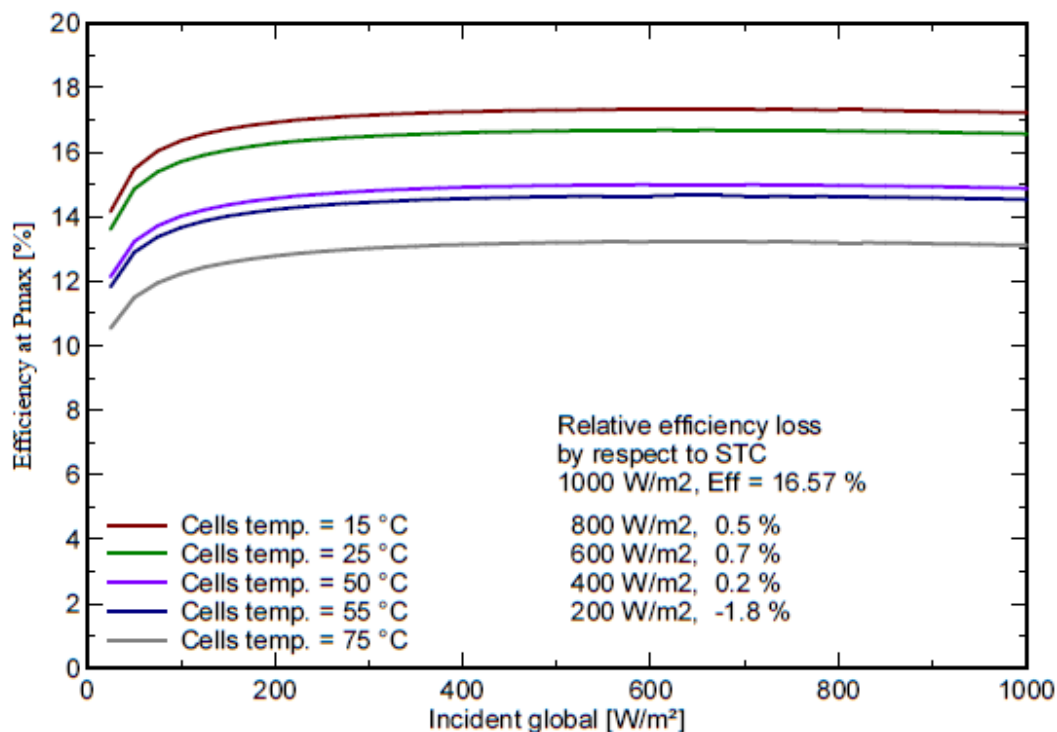
Characteristics of a PV module

Manufacturer, model : **Znshine, ZXP6-D72-325/P_OPTIMIZED**
Data source : **Manufacturer**

STC power (manufacturer)	Pnom	325 Wp	Technology	Si-poly
Module size (W x L)	0.992 x 1.978 m ²		Rough module area	Amodule 1.96 m ²
Number of cells	1 x 72		Sensitive area (cells)	Acells 1.75 m ²
Specifications for the model (manufacturer or measurement data)				
Reference temperature	TRef	25 °C	Reference irradiance	GRef 1000 W/m ²
Open circuit voltage	Voc	45.6 V	Short-circuit current	Isc 9.27 A
Max. power point voltage	Vmpp	37.3 V	Max. power point current	Impp 8.71 A
=> maximum power	Pmpp	325.1 W	Isc temperature coefficient	mulsc 5.6 mA/°C
One-diode model parameters				
Shunt resistance	Rshunt	350 ohm	Diode saturation current	IoRef 0.009 nA
Serie resistance	Rserie	0.38 ohm	Voc temp. coefficient	MuVoc -156 mV/°C
			Diode quality factor	Gamma 0.89
Specified Pmax temper. coeff.	muPMaxR	-0.41 %/°C	Diode factor temper. coeff.	muGamma 0.000 1/°C

Model results for standard conditions (STC: T=25°C, G=1000 W/m², AM=1.5)				
Max. power point voltage	Vmpp	37.1 V	Max. power point current	Impp 8.76 A
Maximum power	Pmpp	325.1 Wc	Power temper. coefficient	muPmpp -0.40 %/°C
Efficiency(/ Module area)	Eff_mod	16.6 %	Fill factor	FF 0.770
Efficiency(/ Cells area)	Eff_cells	18.6 %		

PV module: Znshine, ZXP6-D72-325/P_OPTIMIZED



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Characteristics of a PV module				
Manufacturer, model :		Znshine, ZXP6-D72-320/P_OPTIMIZED		
Data source :		Manufacturer		
STC power (manufacturer)	Pnom	320 Wp	Technology	Si-poly
Module size (W x L)	0.992 x 1.978 m ²		Rough module area	Amodule 1.96 m ²
Number of cells	1 x 72		Sensitive area (cells)	Acells 1.75 m ²
Specifications for the model (manufacturer or measurement data)				
Reference temperature	TRef	25 °C	Reference irradiance	GRef 1000 W/m ²
Open circuit voltage	Voc	45.3 V	Short-circuit current	Isc 9.21 A
Max. power point voltage	Vmpp	37.1 V	Max. power point current	Impp 8.62 A
=> maximum power	Pmpp	320.1 W	Isc temperature coefficient	mulsc 5.5 mA/°C
One-diode model parameters				
Shunt resistance	Rshunt	300 ohm	Diode saturation current	IoRef 0.009 nA
Series resistance	Rserie	0.39 ohm	Voc temp. coefficient	MuVoc -155 mV/°C
			Diode quality factor	Gamma 0.89
Specified Pmax temper. coeff.	muPMaxR	-0.41 %/°C	Diode factor temper. coeff.	muGamma 0.000 1/°C
Model results for standard conditions (STC: T=25°C, G=1000 W/m², AM=1.5)				
Max. power point voltage	Vmpp	36.9 V	Max. power point current	Impp 8.68 A
Maximum power	Pmpp	320.1 Wc	Power temper. coefficient	muPmpp -0.40 %/°C
Efficiency(/ Module area)	Eff_mod	16.3 %	Fill factor	FF 0.767
Efficiency(/ Cells area)	Eff_cells	18.3 %		
PV module: Znshine, ZXP6-D72-320/P_OPTIMIZED				

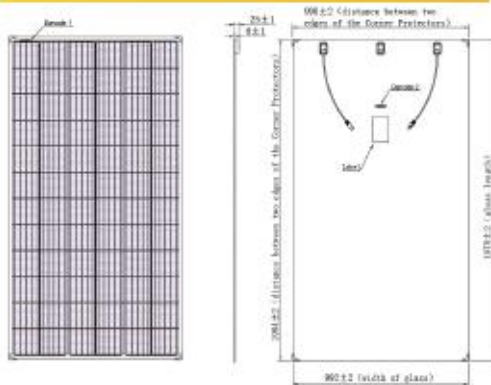
3.0 APPENDIX

Appendix A: ZXP6-D72-325/P and ZXP6-D72-320/P datasheet

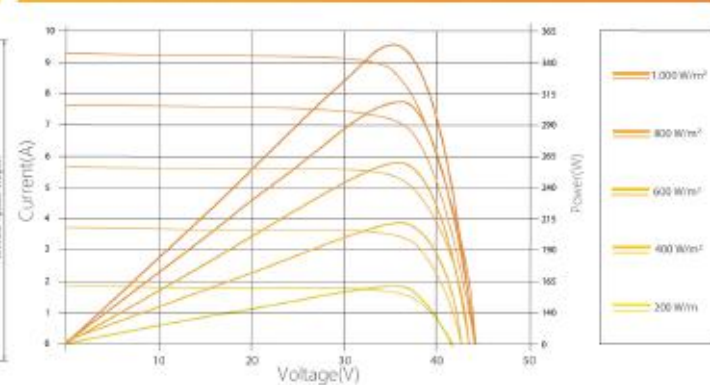
ZXP6 D72/320-340



Dimension of the PV module



I-V Curves of the PV module



Electrical data

Model	ZXP6-D72-320/P	ZXP6-D72-325/P	ZXP6-D72-330/P	ZXP6-D72-335/P	ZXP6-D72-340/P
Nominal Power Watt $P_{max}(W_p)$	320	325	330	335	340
Power Output Tolerance $P_{max}(\%)$	0~+3	0~+3	0~+3	0~+3	0~+3
Maximum Power Voltage $V_{mp}(V)$	37.13	37.32	37.50	37.69	37.87
Maximum Power Current $I_{mp}(A)$	8.62	8.71	8.80	8.89	8.98
Open Circuit Voltage $V_{oc}(V)$	45.33	45.55	45.77	45.99	46.21
Short Circuit Current $I_{sc}(A)$	9.21	9.27	9.33	9.39	9.45
Module Efficiency $\eta_m(\%)$	16.31	16.56	16.82	17.07	17.33

Mechanical data

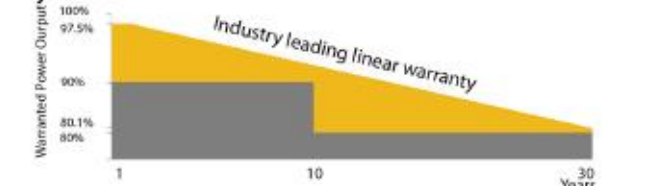
Solar cells	Poly 156×156 / 156.75×156.75 mm
Cells orientation	72 (6×12)
Module dimension	1978×992×25 mm(Frameless,JB Included)
Weight	28 kg
Glass	2.0mm/2.5mm heat strengthened glass
Junction box	IP 68, 3 diodes
Cables	4 mm ² , 350 mm
Connectors	MC4-compatible

Temperature ratings

Nominal Operating Cell Temperature	45°C ±2°C
Temperature coefficient of P_{max}	-0.41%/K
Temperature coefficient of V_{oc}	-0.33%/K
Temperature coefficient of I_{sc}	0.06%/K

Warranty information

30 years output warranty(polycrystalline): 2.5% in the 1st year, thereafter 0.6% per year ending with 80.1% in the 30th year.



Working conditions

Maximum system voltage	1000 / 1500 V DC
Operating temperature	-40°C ~ +85°C
Maximum series fuse	15 A
Maximum load (snow/wind)	5400 Pa / 2400 Pa

Packaging information

Modules per box	33 pcs.
Modules per 40' HQ container	726 pcs.

Measurement Tolerance STC: ±3% (P_{max}), ±10% (V_{oc} , I_{sc} , V_{mp} , I_{mp}). Values at Standard Test Conditions STC(Air Mass AM1.5, Irradiance 1000W/m², Cell Temperature 25°C) | Remark: please read safety and installation instructions before using the product. | Subject to change without prior notice. © ZNSHINE SOLAR 2018 | Version: ZXP6-D72-1805.E